NSN 5962-01-374-0104

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View Online at https://aerobasegroup.com/nsn/5962-01-374-0104

view Offiline at https://defobasegroup.com/nsn/3302-01-3/4-0104
Body Length:
Between 1.140 inches and 1.180 inches
Body Width:
Between 1.140 inches and 1.180 inches
Body Height:
Between 0.070 inches and 0.145 inches
Maximum Power Dissipation Rating:
2.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Burn in and monolithic and hermetically sealed and asynchronous
Inclosure Material:
Ceramic
Inclosure Configuration:
Pin grid array
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Case Outline Source And Designator:
P-ac mil-m-38510
Current Rating Per Characteristic:
250.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source
Capitance Rating Per Characteristic:
11.00 input picofarads
Time Rating Per Chacteristic:
70.00 nanoseconds write-cycle width
Memory Device Type:
Ram
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
68 pin
Shelf Life:
N/a
Unit Of Measure:

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Demilitarization:

No

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